# Lab 138 - Transistors and Amplifiers

## 27 November 2014

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## 1 Ic-Uce-characteristics

### 1.1 Circuit

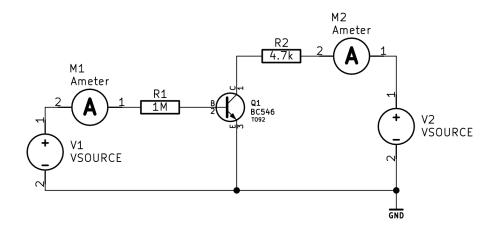


Figure 1: Measurement setup

### 1.1.1 Fixed collector voltage

With the collector resistor R2 left out or shorted, an adjustable power supply is connected directly across the collector-emitter junction, fixing the collector voltage. First we get the base currents for known collector currents. Adjusting voltage V1 translates to varying the base current Ib and in turn the collector current Ic. The transistor used is a BC547C.

### 1.1.2 Measurements

Ic (mA)	Ib (µA)
0.5	1.14
1.0	2.11
1.8	3.72

Table 1: Measurement of base current vs collector current

The base current is then held at a constant value and the collector-emitter voltage is swept over a range of 0-10V in 1V steps. The results is given in the

plot.

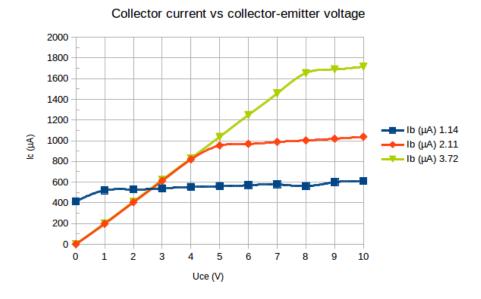


Figure 2: Ic-Uce results

## 1.1.3 Simulation

Spice circuit simulation confirms that measurements reflect typical bjt characteristics. The program used is Linear Technology Itspice, models extracted from transistor datasheet parameters.

## 2 Quiescent conditions

## 2.1 Circuit

 $E=10V~Rc=4.7k\Omega$ 

### 2.1.1 Curve

TODO

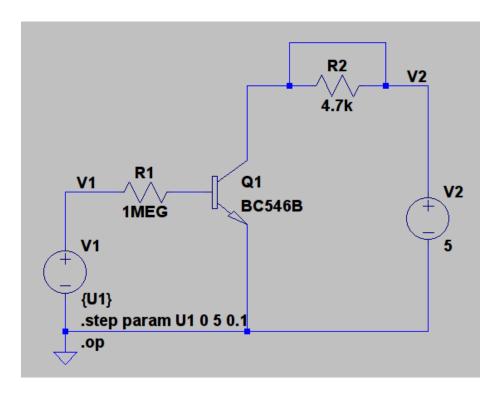


Figure 3: Ltspice schematic

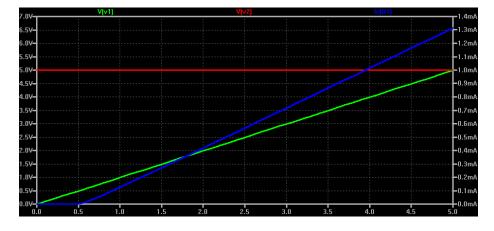


Figure 4: Ltspice simulation of Ic-Uce-characteristics

# TODO!

Figure 5: TODO

## 3 Uce/Ib transfer function

Examine the output signal of the first circuit. Determine the linearity of the output, as in the relation of Uce to Ib. Uses the measurement setup and circuit shown in Figure 1.

# TOD0!

Figure 6: TODO

## 4 Ic/Ib characteristics and current amplification

#### 4.1 Measurements

## 4.2 Comments

TODO: Comment the curve, calculate current amplification factor deltaIc/deltaIb in regions of interest.

# TODO!

Figure 7: Ic as a function of Ib

## 5 BJT biasing

Rb	Ve	Ve	Rc
$390 \mathrm{k}\Omega$	00	00	00
$470 \mathrm{k}\Omega$	00	00	00
$560 k\Omega$	00	00	00
$680 \mathrm{k}\Omega$	00	00	00
$820 k\Omega$	00	00	00
$1 \mathrm{M}\Omega$	00	00	00

Table 2: Bias resistor with bias voltages

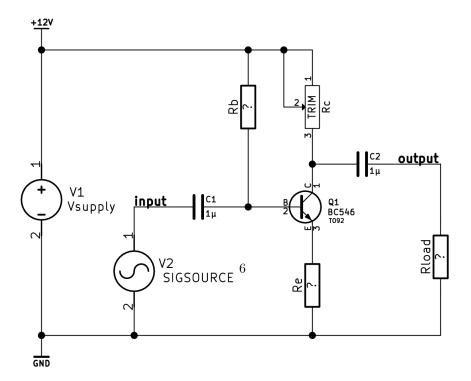


Figure 8: BJT biasing circuit

## 6 BJT amplifier

## 6.0.1 Amplification

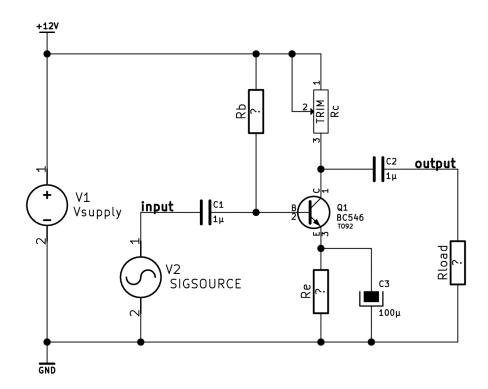


Figure 9: AC bypassed BJT amplifier

	Without AC bypass	AC bypassed
Input voltage (mVtt)	111	111
Output voltage (Vtt)	111	111
Voltage gain (multiple)	111	111
Voltage gain (dB)	111	111
Phase shift (degrees)	111	111

Table 3: Amplifier gain measurements

### 6.0.2 Frequency response

#### 6.0.3 Improved biasing

The one resistor base bias is in practice not very reliable as it is dependant on transistor beta. A more practical design that scales better for production adds a second resistor, forming a voltage divider that fixes the base at a suitable level. For maximum dynamic range half of Vsupply, plus a diode drop to compensate for the base-emitter voltage.

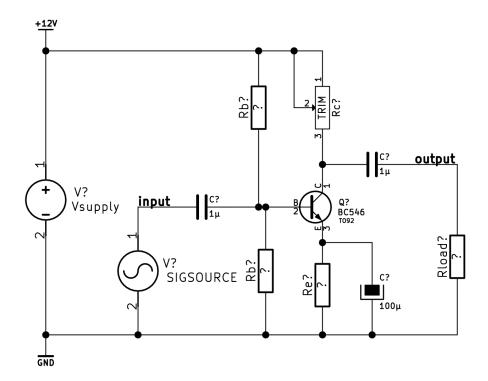


Figure 10: Voltage divider bias

#### 6.0.4 "Noiseless" biasing

For small signals and high input impedance, the biasing can be improved further in terms of bias voltage "stiffness" and power supply noise rejection. The bias voltage is derived from a separate low impedance voltage divider, heavily filtered and almost a short circuit as far as AC signals are concerned. The bias voltage is tapped with a higher value resistor which effectively sets the input impedance of the stage.

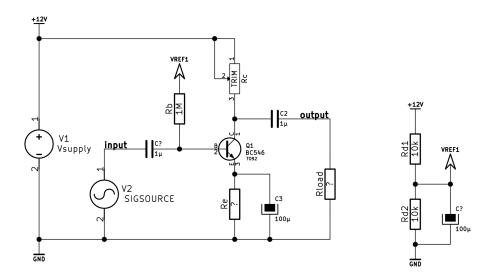


Figure 11: Voltage divider with filtered voltage reference